



MBR20100 THRU MBR20200

RoHS
COMPLIANT

肖特基二极管 Schottky Rectifier

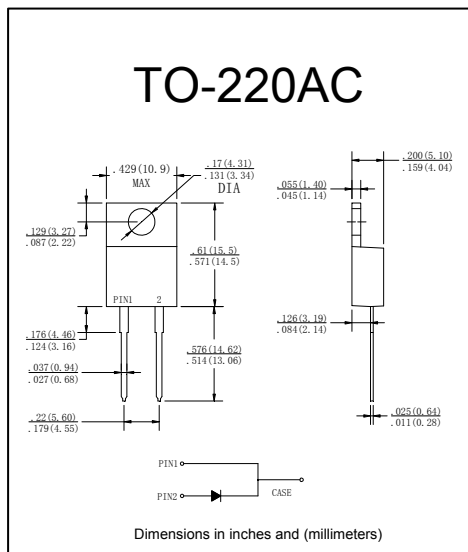
■特征 Features

- I_o 20A
- V_{RRM} 100V-200V
- 耐正向浪涌电流能力高
High surge current capability
- 封装：模压塑料
Cases: Molded plastic

■用途 Applications

- 整流用 Rectifier

■外形尺寸和印记 Outline Dimensions and Mark



■极限值（绝对最大额定值）

Limiting Values (Absolute Maximum Rating)

参数名称 Item	符号 Symbol	单位 Unit	测试条件 Test Conditions	MBR20		
				100	150	200
反向重复峰值电压 Repetitive Peak Reverse Voltage	V_{RRM}	V		100	150	200
平均整流输出电流 Average Rectified Output Current	I_o	A	正弦半波 60Hz, 电阻负载, T_c (Fig.1) 60Hz Half-sine wave, Resistance load, T_c (Fig.1)	20.0		
正向（不重复）浪涌电流 Surge(Non-repetitive)Forward Current	I_{FSM}	A	正弦半波 60Hz, 一个周期, $T_a=25^\circ\text{C}$ 60Hz Half-sine wave, 1 cycle, $T_a=25^\circ\text{C}$	150		
结温 Junction Temperature	T_J	$^\circ\text{C}$		-55 ~ +150		
储存温度 Storage Temperature	T_{STG}	$^\circ\text{C}$		-55 ~ +150		

■电特性（ $T_a=25^\circ\text{C}$ 除非另有规定）

Electrical Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

参数名称 Item	符号 Symbol	单位 Unit	测试条件 Test Condition		MBR20		
					100	150	200
正向峰值电压 Peak Forward Voltage	V _F	V	I _F =10.0A		0.85	1.02	
反向漏电流 Peak Reverse Current	I _{RRM1}	mA	V _{RM} =V _{RRM}	T _a =25℃	0.1		
	I _{RRM2}			T _a =125℃	10		
热阻(典型) Thermal Resistance(Typical)	R _{θJ-C}	℃/W	结和壳之间 Between junction and case		2.0 ¹⁾		

备注: Notes:

¹⁾ 热电阻从结到本体每管脚

Thermal resistance from junction to case per leg

■特性曲线（典型） Characteristics(Typical)

图1：正向电流降额曲线

FIG1: IF (AV) --Tc Derating

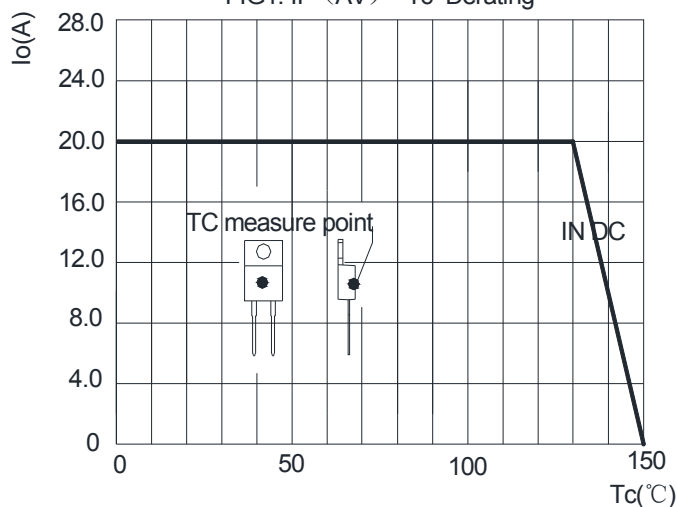


图2：最大正向浪涌冲击耐受力

FIG.2: MAXIMUM NON-REPETITIVE FORWARD URGE CURRENT

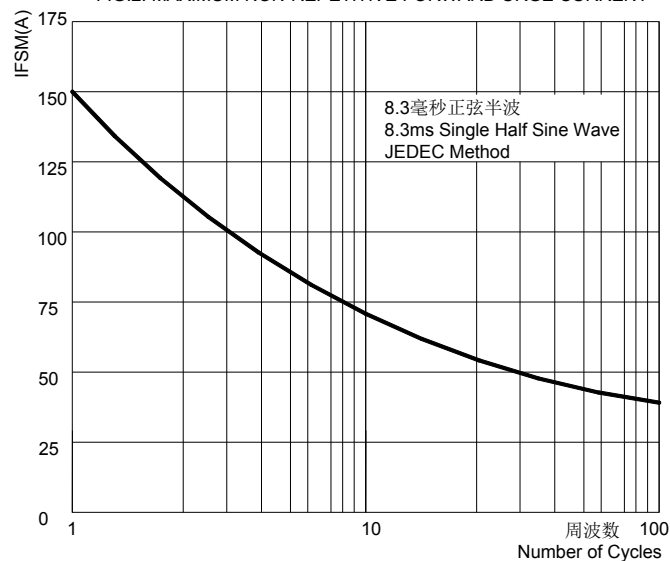


图3：典型正向特性曲线

FIG.3: TYPICAL FORWARD CHARACTERISTICS

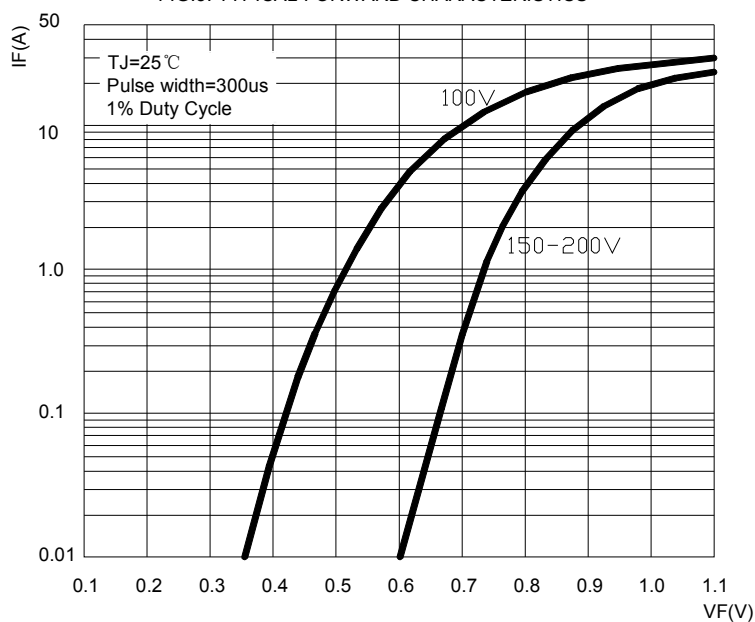


图4：典型反向特性曲线

FIG.4: TYPICAL REVERSE CHARACTERISTICS

